1 Scope

The present specifications shall apply to an RM1.

2 Outline

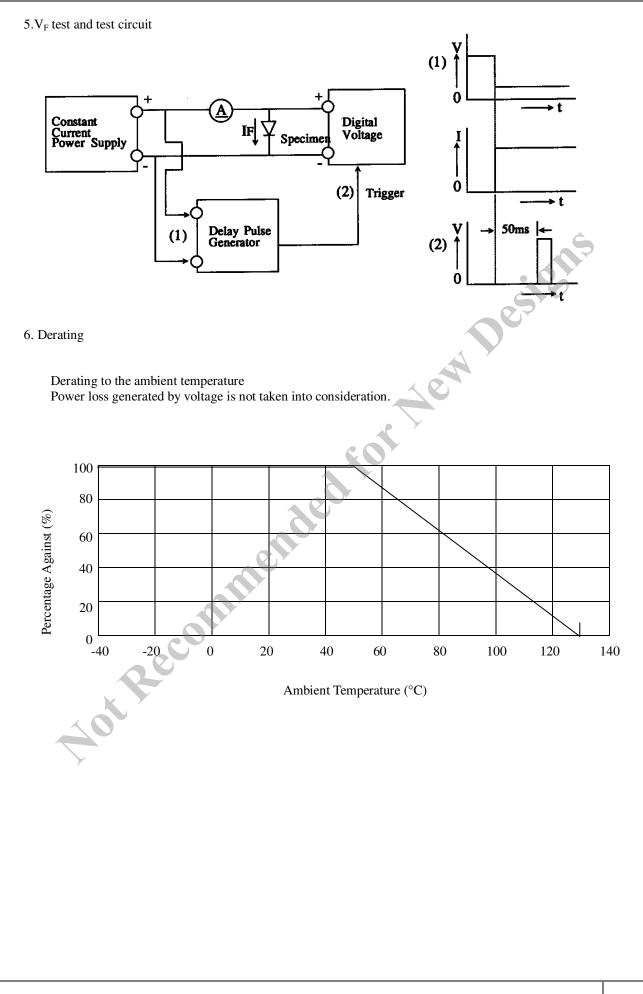
Туре	Silicon Diode (Mesa Type)				
Structure	Resin Molded Flammability : UL94V-0(Equivalent)				
Applications	Commercial Frequency Rectification				

3 Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	V _{RSM}	V	400	¥
2	Peak Reverse Voltage	V _{RM}	V	400	
3	Average Forward Current	I _{F(AV)}	А	1.0	Refer to derating curve in Section 6
4	Peak Surge Forward Current	I _{FSM}	А	50	10ms. Half sine wave, one shot
5	I ² t Limiting Value	I^2t	A ² s	12.5	1ms≦t≦10ms
6	Junction Temperature	Tj	°C	-40 to +150	
7	Storage Temperature	T _{stg}	°C	-40 to +150	

4 Electrical characteristics (Ta=25°C, unless otherwise specified)

No.	Item	Symbol	Unit	Rating	Conditions
1	Forward Voltage Drop	$V_{\rm F}$	V	0.95 max.	I _F =1.0A
2	Reverse Leakage Current	I _R	μΑ	5 max.	V _R =V _{RM}
3	Reverse Leakage Current Under High Temperature	H∙I _R	μΑ	50 max.	$V_R = V_{RM}, T_j = 100^{\circ}C$
4	Thermal Resistance	$R_{th(j\text{-}l)}$	°C/W	15 max.	Between Junction and Lead



- 7. Dimensions, inner structure and marking
 - 7.1 Dimensions refer

